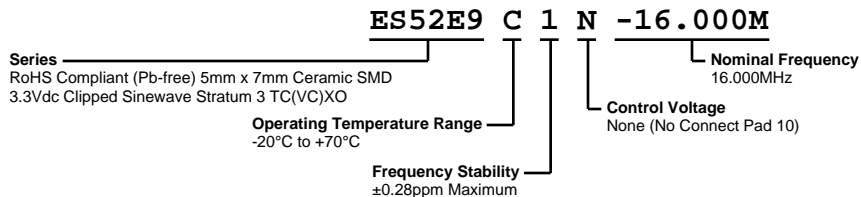


# ES52E9C1N-16.000M



## ELECTRICAL SPECIFICATIONS

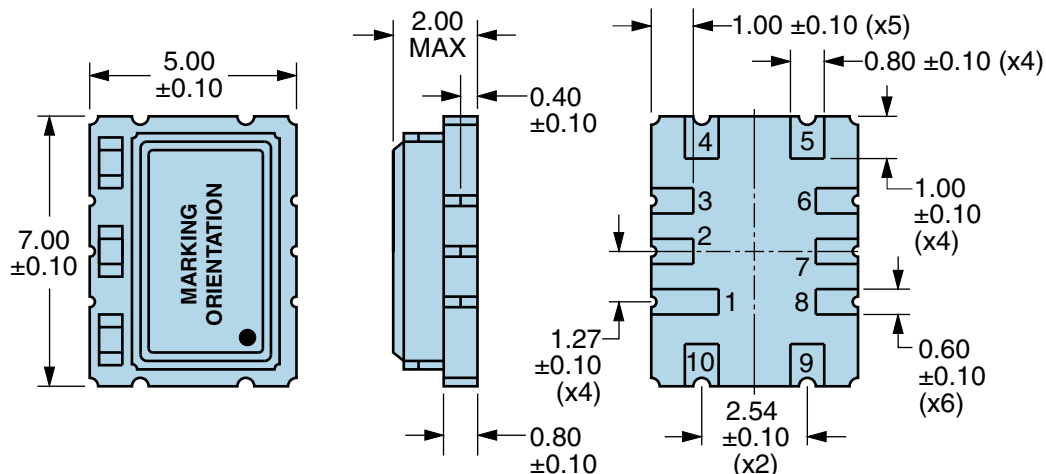
Nominal Frequency	16.000MHz
Total Frequency Tolerance	±4.6ppm Maximum (Inclusive of Frequency Tolerance, Frequency Stability, Vdd (±1%), Load (±5%), solder reflow, and 20 year aging)
Frequency Stability	±0.28ppm Maximum (Measured at Vdd=3.3Vdc and Vc=1.5Vdc)
Operating Temperature Range	-20°C to +70°C
Supply Voltage	3.3Vdc ±5%
Total Holdover Stability	±0.37ppm Maximum (Inclusive of Frequency Stability and 24 hours aging)
Input Current	2.0mA Maximum
Output Voltage	0.8Vp-p Clipped Sinewave Minimum (External DC-Cut capacitor required, 150pF recommended)
Load Drive Capability	10kOhms // 10pF
Output Logic Type	Clipped Sinewave
Control Voltage	None (No Connect Pad 10)
Phase Noise	-80dBc/Hz at 10Hz Offset, -115dBc/Hz at 100Hz Offset, -135dBc/Hz at 1kHz Offset, and -145dBc/Hz at >=10kHz Offset (Typical Values at 12.800MHz)
RMS Phase Jitter	1pSec Maximum (Fj = 12kHz to 20MHz)
Start Up Time	10mSec Maximum
Storage Temperature Range	-40°C to +125°C

## ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

Fine Leak Test	MIL-STD-883, Method 1014 Condition A
Gross Leak Test	MIL-STD-883, Method 1014 Condition C
Mechanical Shock	MIL-STD-202, Method 213 Condition C
Resistance to Soldering Heat	MIL-STD-202, Method 210
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003
Temperature Cycling	MIL-STD-883, Method 1010
Vibration	MIL-STD-883, Method 2007 Condition A

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## MECHANICAL DIMENSIONS (all dimensions in millimeters)

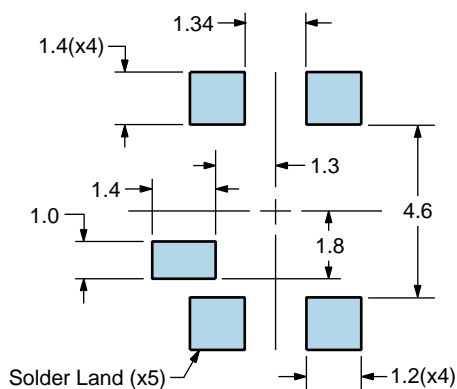


PIN	CONNECTION
1	Do Not Connect
2	Do Not Connect
3	Do Not Connect
4	Ground
5	Output
6	Do Not Connect
7	Do Not Connect
8	Do Not Connect
9	Supply Voltage
10	No Connect

LINE	MARKING
1	<b>EXX.XXX</b> <i>E=Ecliptek Designator XX.XXX=Nominal Frequency in MHz</i>
2	<b>XXYYZ</b> <i>XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year</i>

## Suggested Solder Pad Layout

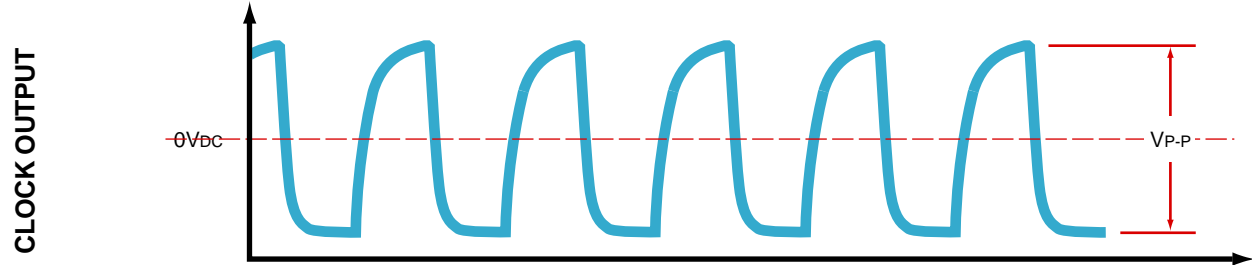
All Dimensions in Millimeters



All Tolerances are  $\pm 0.1$

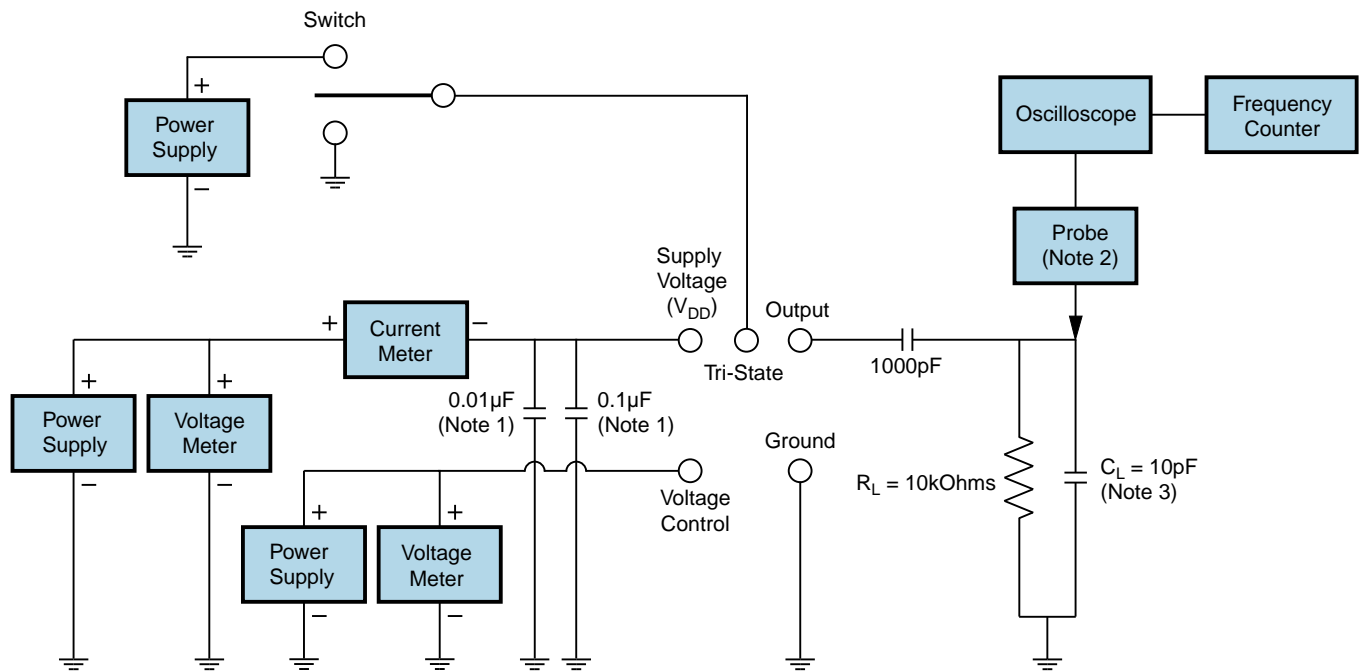
# ES52E9C1N-16.000M

## OUTPUT WAVEFORM



# ES52E9C1N-16.000M

## Test Circuit for Voltage Control Option



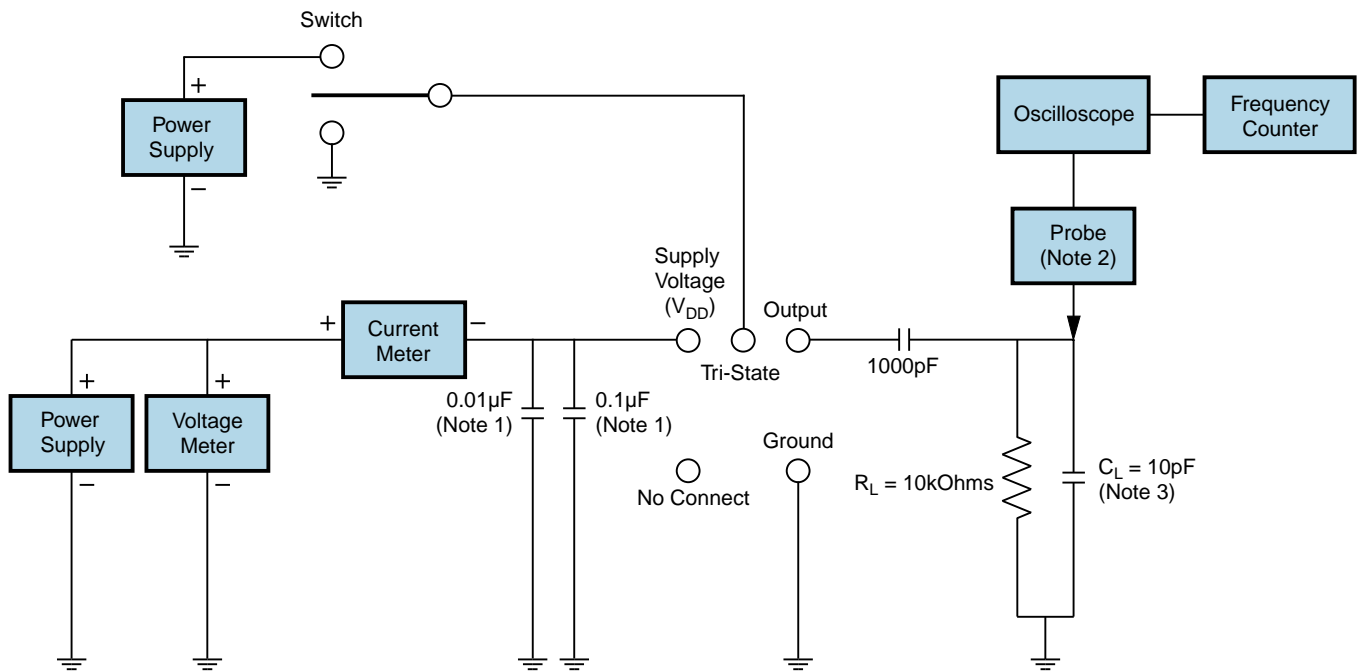
Note 1: An external  $0.1\mu\text{F}$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu\text{F}$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.

Note 2: A low capacitance ( $<12\text{pF}$ ), 10X attenuation factor, high impedance ( $>10\text{Mohms}$ ), and high bandwidth ( $>300\text{MHz}$ ) passive probe is recommended.

Note 3: Capacitance value  $C_L$  includes sum of all probe and fixture capacitance.

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## Test Circuit for No Connect Option

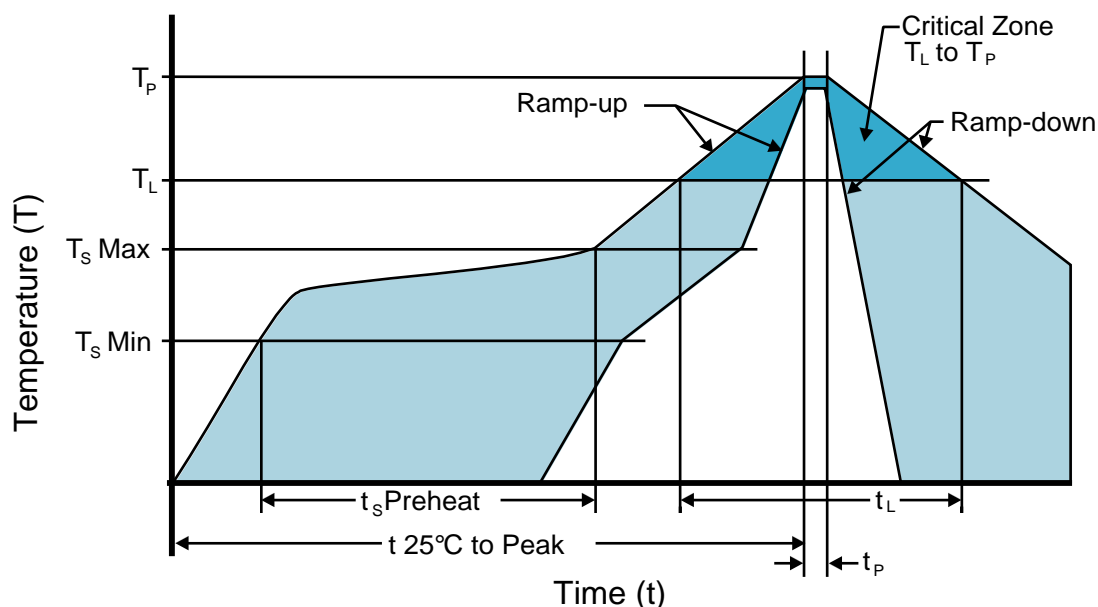


Note 1: An external 0.1μF low frequency tantalum bypass capacitor in parallel with a 0.01μF high frequency ceramic bypass capacitor close to the package ground and V<sub>DD</sub> pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value C<sub>L</sub> includes sum of all probe and fixture capacitance.

## Recommended Solder Reflow Methods



### High Temperature Infrared/Convection

**$T_s \text{ MAX}$  to  $T_L$  (Ramp-up Rate)** 3°C/second Maximum

#### Preheat

- Temperature Minimum ( $T_s \text{ MIN}$ ) 150°C
- Temperature Typical ( $T_s \text{ TYP}$ ) 175°C
- Temperature Maximum ( $T_s \text{ MAX}$ ) 200°C
- Time ( $t_s \text{ MIN}$ ) 60 - 180 Seconds

**Ramp-up Rate ( $T_L$  to  $T_p$ )** 3°C/second Maximum

#### Time Maintained Above:

- Temperature ( $T_L$ ) 217°C
- Time ( $t_L$ ) 60 - 150 Seconds

**Peak Temperature ( $T_p$ )** 260°C Maximum for 10 Seconds Maximum

**Target Peak Temperature ( $T_p \text{ Target}$ )** 250°C +0/-5°C

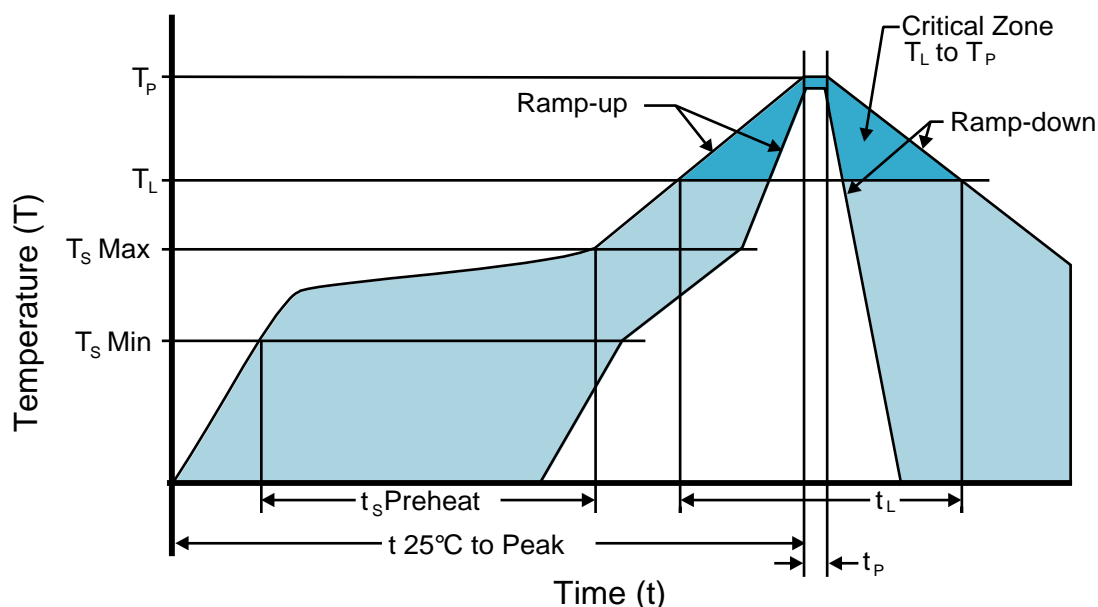
**Time within 5°C of actual peak ( $t_p$ )** 20 - 40 seconds

**Ramp-down Rate** 6°C/second Maximum

**Time 25°C to Peak Temperature (t)** 8 minutes Maximum

**Moisture Sensitivity Level** Level 1

## Recommended Solder Reflow Methods



### Low Temperature Infrared/Convection 230°C

**T<sub>s</sub> MAX to T<sub>L</sub> (Ramp-up Rate)** 5°C/second Maximum

#### Preheat

- Temperature Minimum (T<sub>s</sub> MIN) N/A  
 - Temperature Typical (T<sub>s</sub> TYP) 150°C  
 - Temperature Maximum (T<sub>s</sub> MAX) N/A  
 - Time (t<sub>s</sub> MIN) 30 - 60 Seconds

**Ramp-up Rate (T<sub>L</sub> to T<sub>P</sub>)** 5°C/second Maximum

#### Time Maintained Above:

- Temperature (T<sub>L</sub>) 150°C  
 - Time (t<sub>L</sub>) 200 Seconds Maximum

**Peak Temperature (T<sub>P</sub>)** 230°C Maximum

**Target Peak Temperature (T<sub>P</sub> Target)** 230°C Maximum 2 Times

**Time within 5°C of actual peak (t<sub>p</sub>)** 10 seconds Maximum 2 Times

**Ramp-down Rate** 5°C/second Maximum

**Time 25°C to Peak Temperature (t)** N/A

**Moisture Sensitivity Level** Level 1

### Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

### High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.